

10A Avg.

30 Volts

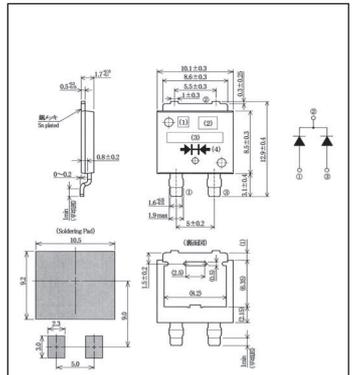
SBD

UCQ10A03

■最大定格 Maximum Ratings (Ta=25°C : unless otherwise specified)

Item	Symbol	Condition	Unit
くり返しピーク逆電圧 Repetitive Peak Reverse Voltage	$V_{RRM}$	30	V
平均整流電流 Average Rectified Forward Current	$I_O$	50Hz 正弦全波, 抵抗負荷 50Hz Full Sine Wave, Resistance Load	10
実効順電流 R.M.S. Forward Current	$I_F(RMS)$	11.1	A
サージ順電流 Surge Forward Current	$I_{FSM}$	120 50Hz正弦全波 1 サイクル 非くり返し 50Hz Full Sine Wave 1 cycle, Non-repetitive	A
動作接合温度範囲 Operating Junction Temperature Range	$T_{jw}$	-40~+150	°C
保存温度範囲 Storage Temperature Range	$T_{stg}$	-40~+150	°C

■OUTLINE DRAWING(mm)



■電氣的・熱的特性 Electrical/Thermal Characteristics

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
ピーク逆電流 Peak Reverse Current	$I_{RM}$	$T_j=25^\circ\text{C}$ , $V_{RM}=V_{RRM}$ , 一素子あたり Per Diode	—	—	1	mA
ピーク順電圧 Peak Forward Voltage	$V_{FM}$	$T_j=25^\circ\text{C}$ , $I_{FM}=5\text{A}$ , 一素子あたり Per Diode	—	—	0.46	V
熱抵抗 Thermal Resistance	$R_{th(j-c)}$	接合部・ケース間 Junction to Case	—	—	2.5	°C/W

■定格・特性曲線

FIG.1 順電圧特性  
FORWARD CURRENT VS. VOLTAGE

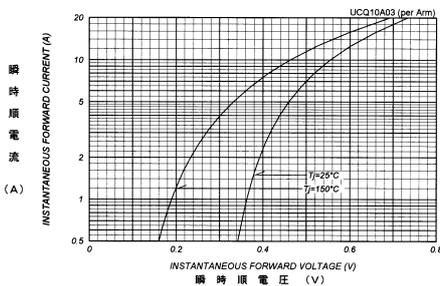


FIG.2 平均順電力損失特性  
AVERAGE FORWARD POWER DISSIPATION

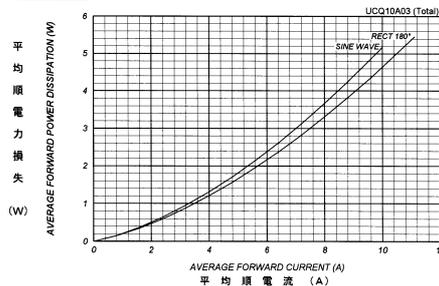


FIG.3 ピーク逆電流 - ピーク逆電圧特性  
PEAK REVERSE CURRENT VS. PEAK REVERSE VOLTAGE

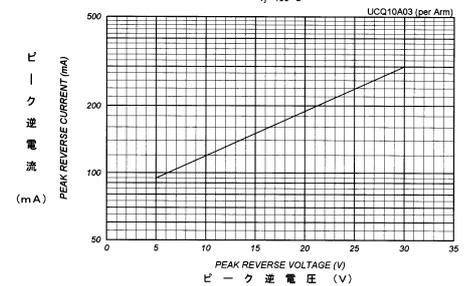


FIG.4 平均逆電力損失  
AVERAGE REVERSE POWER DISSIPATION

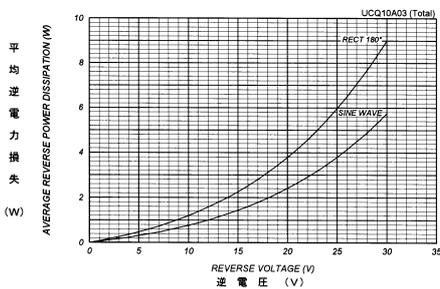


FIG.5 平均順電流 - ケース温度定格  
AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

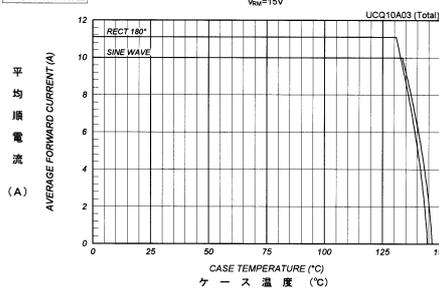


FIG.6 サージ順電流定格  
SURGE CURRENT RATINGS

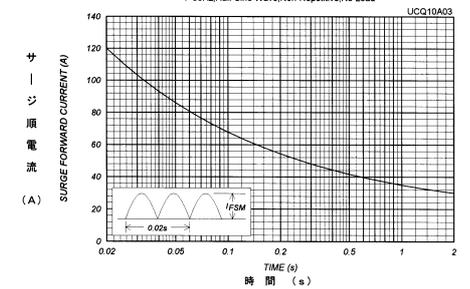


FIG.7 接合容量特性  
JUNCTION CAPACITANCE VS. REVERSE VOLTAGE

